ESD Protection Diode

Low Capacitance ESD Protection Diodes for High Speed Data Lines

The ESD9101 is designed to protect a single high speed data line from ESD. Ultra-low capacitance and low ESD clamping voltage via SCR technology make this device an ideal solution for protecting voltage sensitive high speed data lines. The SOD-923 mico-package allows for easy PCB layout and the ability to be placed in space constrained applications where board area comes at a premium.

Features

- Low Capacitance (0.5 pF Max, I/O to GND)
- Protection for the Following Standards: IEC 61000-4-2 (Level 4) & ISO 10605
- Low ESD Clamping Voltage
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- USB 3.0/3.1
- HDMI 1.3/1.4/2.0
- DisplayPort
- GPS Antenna

Rating	Symbol	Value	Unit		
Operating Junction Temperature Range	ТJ	-55 to +150	°C		
Storage Temperature Range	T _{stg}	-55 to +150	°C		
Lead Solder Temperature – Maximum (10 Seconds)	ΤL	260	°C		
$\begin{array}{l} \text{IEC 61000-4-2 Contact} \\ \text{IEC 61000-4-2 Air} \\ \text{ISO 10605 150 pF/2 } k\Omega \\ \text{ISO 10605 330 pF/2 } k\Omega \\ \text{ISO 10605 330 pF/330 } \Omega \end{array}$	ESD	$\pm 25 \\ \pm 25 \\ \pm 30 \\ \pm 30 \\ \pm 20$	kV		

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

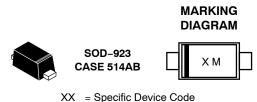
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

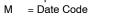
See Application Note AND8308/D for further description of survivability specs.



ON Semiconductor®

www.onsemi.com

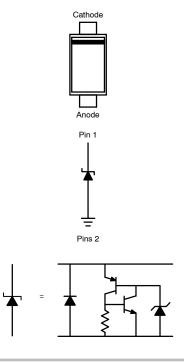




= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONFIGURATIONS AND SCHEMATICS



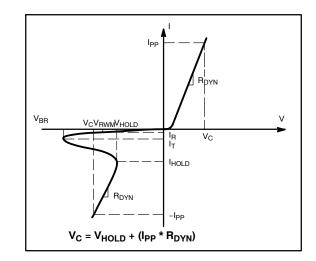
ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

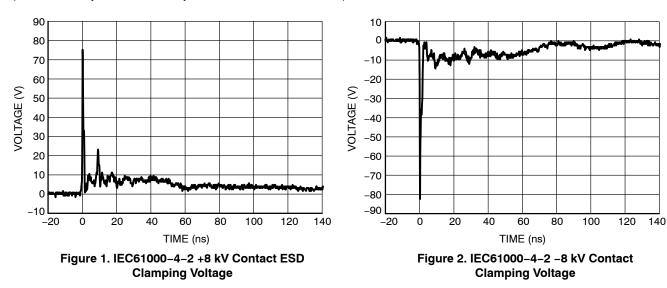
Symbol	Parameter
V _{RWM}	Working Peak Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current
V _{HOLD}	Holding Reverse Voltage
I _{HOLD}	Holding Reverse Current
R _{DYN}	Dynamic Resistance
I _{PP}	Maximum Peak Pulse Current
V _C	Clamping Voltage @ I _{PP} V _C = V _{HOLD} + (I _{PP} * R _{DYN})



ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise specified)

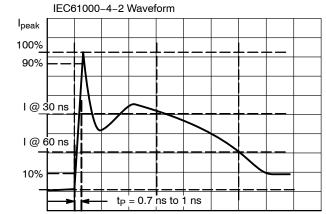
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	I/O Pin to GND			5.0	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, I/O Pin to GND	5.3	7.0	8.0	V
Reverse Leakage Current	I _R	V _{RWM} = 5.0 V, I/O Pin to GND			1.0	μA
Holding Reverse Voltage	V _{HOLD}	I/O Pin to GND		2.2		V
Holding Reverse Current	I _{HOLD}	I/O Pin to GND	65	97		mA
Clamping Voltage	V _C	IEC61000-4-2, ±8 KV Contact	See Figures 1 and 2		V	
Clamping Voltage TLP V _C		I _{PP} = 8 A I _{PP} = -8 A		5.0 -4.0		V
		I _{PP} = 16 A I _{PP} = –16 A		7.0 -7.0		
Dynamic Resistance	R _{DYN}	I/O Pin to GND GND to I/O Pin		0.30 0.38		Ω
Junction Capacitance C _J		V_R = 0 V, f = 1 MHz between I/O Pins and GND V_R = 0 V, f = 2.5 GHz between I/O Pins and GND V_R = 0 V, f = 5.0 GHz between I/O Pins and GND		0.36 0.36 0.36	0.50 0.45 0.45	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8





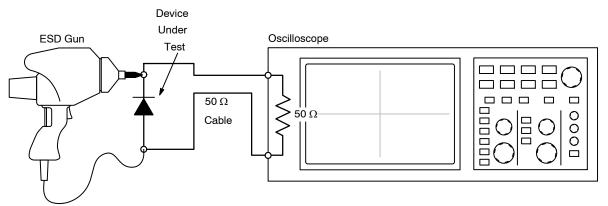


Figure 4. Diagram of ESD Clamping Voltage Test Setup

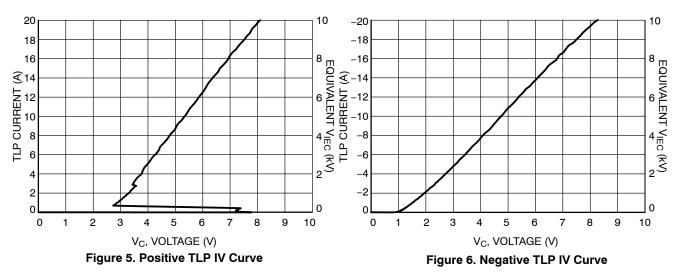
The following is taken from Application Note AND8307/D – Characterization of ESD Clamping Performance.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000–4–2 waveform. Since the IEC61000–4–2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

ESD9101



NOTE: TLP parameter: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 300$ ps, averaging window: $t_1 = 30$ ns to $t_2 = 60$ ns. V_{IEC} is the equivalent voltage stress level calculated at the secondary peak of the IEC 61000–4–2 waveform at t = 30 ns with 2 A/kV. See TLP description below for more information.

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 7. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 8 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to AND9007/D.

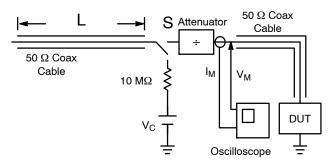


Figure 7. Simplified Schematic of a Typical TLP System

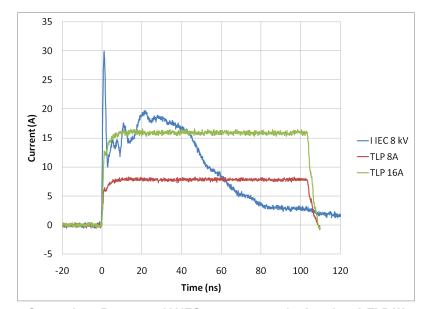


Figure 8. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

ESD9101

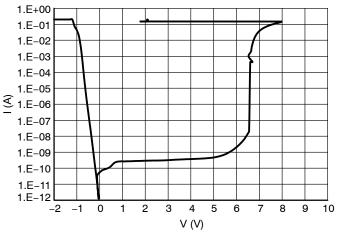
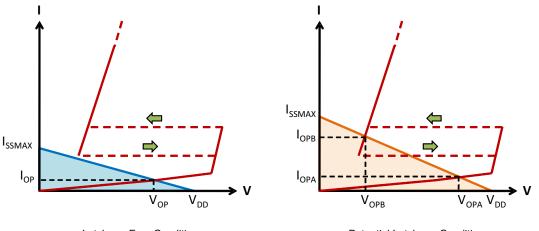


Figure 9. IV Characteristics

Latch-Up Considerations

ON Semiconductor's 9100 series of ESD protection devices utilize a snap-back, SCR type structure. By using this technology, the potential for a latch-up condition was taken into account by performing load line analyses of common high speed serial interfaces. Example load lines for latch-up free applications and applications with the potential for latch-up are shown below with a generic IV characteristic of a snapback, SCR type structured device overlaid on each. In the latch-up free load line case, the IV characteristic of the snapback protection device intersects the load-line in one unique point (V_{OP} I_{OP}). This is the only stable operating point of the circuit and the system is

therefore latch-up free. In the non-latch up free load line case, the IV characteristic of the snapback protection device intersects the load-line in two points (V_{OPA} , I_{OPA}) and (V_{OPB} , I_{OPB}). Therefore in this case, the potential for latch-up exists if the system settles at (V_{OPB} , I_{OPB}) after a transient. Due to its high holding current, the ESD9101 is suitable for HDMI and 5 V active antenna applications where previous ESD8000 series devices were not. When designing this part into the application, please note the latch-up considerations by performing a loadline analysis corresponding to the data line and ESD9101's SCR characteristics. For a more in-depth explanation of latch-up considerations please refer to Application Note AND9116/D.



Latch-up Free Condition

Potential Latch-up Condition

Figure 10. Example Load Lines for Latch-up Free Applications and Applications with the Potential for Latch-up

Application	VBR (min) (V)	IH (min) (mA)	VH (min) (∨)
HDMI 1.4/1.3a TMDS	3.465	54.78	1.0
USB 2.0 LS/FS	3.301	1.76	1.0
USB 2.0 HS	0.482	N/A	1.0
USB 3.0/3.1 SS	2.800	N/A	1.0
DisplayPort	3.600	25.00	1.0
GPS (Active)	5.200	80.00	1.0

Table 1. SUMMARY OF SCR REQUIREMENTS FOR LATCH-UP FREE APPLICATIONS

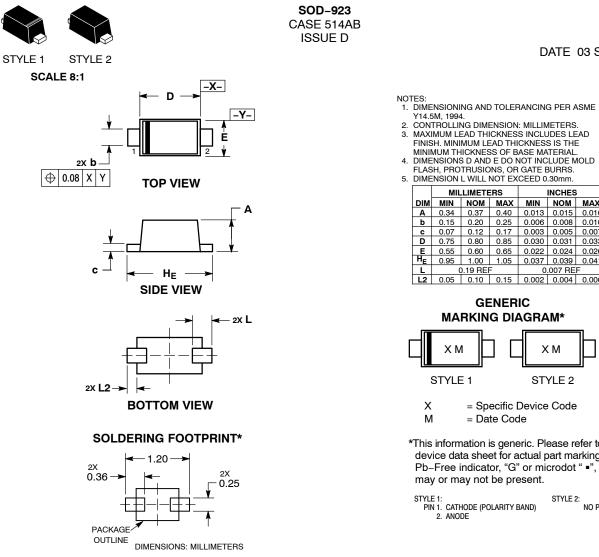
ORDERING INFORMATION

Device	Package	Shipping [†]
ESD9101P2T5G	SOD-923	8000 / Tape & Reel
SZESD9101P2T5G	(Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



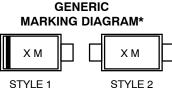
See Application Note AND8455/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



DATE 03 SEP 2020

	MIL	LIMETE	IRS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
Е	0.55	0.60	0.65	0.022	0.024	0.026
HE	0.95	1.00	1.05	0.037	0.039	0.041
L	0.19 REF			0	.007 RE	F
L2	0.05	0.10	0.15	0.002	0.004	0.006



= Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ",

STYLE 2: NO POLARITY

DOCUMENT NUMBER:	98AON23284D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	SOD-923, 1.0X0.6X0.37, MAX	PAGE 1 OF 1	
ON Semiconductor reserves the right the suitability of its products for any pa	to make changes without further notice to any articular purpose, nor does ON Semiconductor	stries, LLC dba ON Semiconductor or its subsidiaries in the United States y products herein. ON Semiconductor makes no warranty, representation r assume any liability arising out of the application or use of any product o cidental damages. ON Semiconductor does not convey any license under	or guarantee regarding r circuit, and specifically

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative